

## **NCE Automotive N-Channel Enhancement Mode Power MOSFET**

### **Description**

The NCEA85H25 uses advanced trench technology and design to provide excellent  $R_{\text{DS}(\text{ON})}$  with low gate charge. It can be used in a wide variety of applications.

## **Application**

- Automotive application
- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

### **General Features**

V<sub>DS</sub> = 85V,I<sub>D</sub> =250A

 $R_{DS(ON)} < 3.5 \text{m}\Omega$  @  $V_{GS} = 10 \text{V}$  (Typ:3.0 m $\Omega$ )

- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high EAS
- Excellent package for good heat dissipation
- 175 °C operating temperature
- Pb-free lead plating;RoHScompliant
- Halogen-freeaccording to IEC61249-2-21
- 100% UIS tested
- 100% ΔVds tested
- AEC-Q101 qualified

TO-220-3L





**Schematic Diagram** 

## **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
A85H25	NCEA85H25	TO-220-3L	-	-	-

## Absolute Maximum Ratings (T<sub>c</sub>=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V <sub>DS</sub>	85	V	
Gate-Source Voltage	V <sub>G</sub> s	±20	V	
Drain Current-Continuous	I <sub>D</sub>	250	Α	
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (100°C)	177	А	
Pulsed Drain Current	I <sub>DM</sub>	1000	А	
Maximum Power Dissipation	P <sub>D</sub>	425	W	
Derating factor		2.33	W/°C	
Single pulse avalanche energy (Note 1)	Eas	2500	mJ	
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 175	°C	

### **Thermal Characteristic**

Parameter	Symbol	Min	Тур	Max	Unit
Thermal Resistance, Junction-to-Case	R <sub>eJC</sub>	-	0.35	0.5	°C/W



## Electrical Characteristics (Tc=25°C unless otherwise noted)

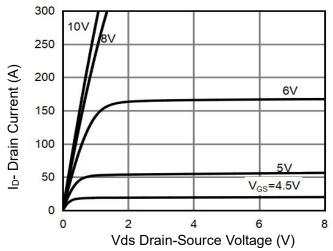
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	<u> </u>					
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	85	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =85V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics	,					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2	3	4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	3.0	3.5	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =20A	-	70	-	S
Dynamic Characteristics (Note4)	,					
Input Capacitance	C <sub>lss</sub>		-	16880	-	PF
Output Capacitance	Coss	V <sub>DS</sub> =40V,V <sub>GS</sub> =0V, F=1.0MHz		863	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>			731	-	PF
Switching Characteristics (Note 2)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	50	-	nS
Turn-on Rise Time	tr	$V_{DD}$ =40V, $R_L$ =0.8 $\Omega$	-	100	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{GEN}$ =2.5 $\Omega$	-	300	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	80	-	nS
Total Gate Charge	Qg	V 40V/ L 00 A	-	296	-	nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =40V,I <sub>D</sub> =20A,	-	76	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V		78	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =20A	-	-	1.2	V
Diode Forward Current	Is	-	-	-	250	Α
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, IF = 100A	-	100	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs	-	210	-	nC

### Notes:

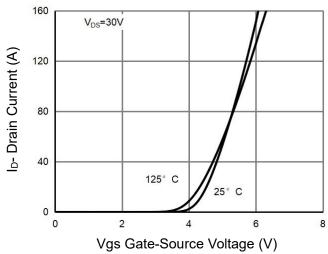
- 1. EAS condition : Tj=25  $^{\circ}\text{C}$  ,VDD=40V,VG=10V,L=0.5mH,Rg=25 $\Omega$
- 2. Guaranteed by design, not subject to production
- 3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of T<sub>J(MAX)</sub>=175°C. The SOA curve provides a single pulse rating.



## **Typical Electrical and Thermal Characteristics (Curves)**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

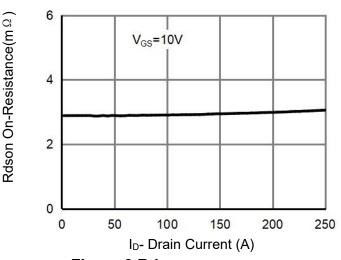


Figure 3 Rdson- Drain Current

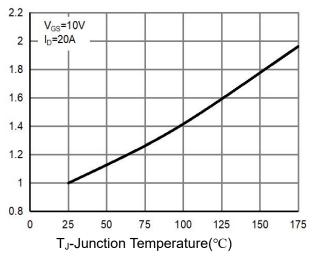


Figure 4 Rdson-JunctionTemperature

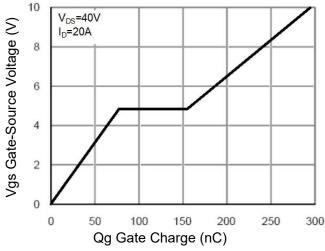


Figure 5 Gate Charge

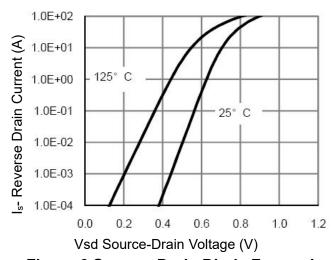
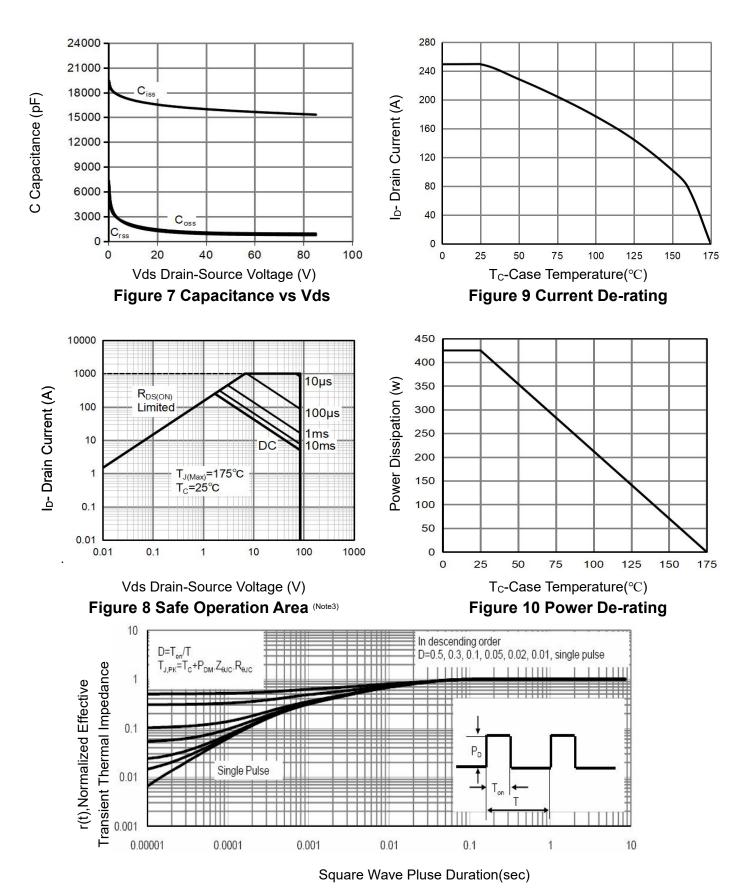


Figure 6 Source- Drain Diode Forward

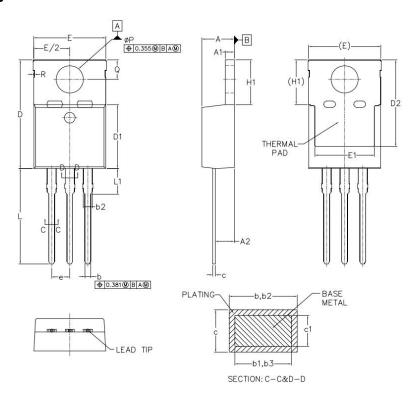




**Figure 11 Normalized Maximum Transient Thermal Impedance** 



# **TO-220-3L Package Information**



Ş	COMMON				
MB	MM				
NY MBOLIN	MIN.	MAX.			
Α	3.556	4.826			
A1	0.508	1.397			
A2	2.032	2.921			
b	0.381	1.016			
b1	0.381	0.965			
b2	1.143	1.778			
b3	1.143	1.727			
С	0.356	0.610			
c1	0.356	0.559			
D	14.224	16.510			
D1	8.382	9.017			
D2	12.042	12.878			
E	9.652	10.668			
E1	6.858	8.890			
е	2.540 BSC.				
H1	5.842	6.858			
L	12.700	14.732			
L1	3.560	4.060			
ØΡ	3.810	3.860			
Q	2.540	3.048			
R	0.12	7 BSC			

## **Revision History**

Revision	Date	Subjects
V1.0	2023.05.17	Product data sheet
V2.0	2023.06.08	R <sub>θJC</sub> Typ Max value

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